



**TPA3122D2** 

SLOS527A-DECEMBER 2007-REVISED DECEMBER 2007

# 15-W STEREO CLASS-D AUDIO POWER AMPLIFIER

# FEATURES

- 10-W/ch into an 4-Ω Load From a 17-V Supply
- 15-W/ch into an 8-Ω Load From a 28-V Supply
- Operates from 10 V to 30 V
- Efficient Class-D Operation
- Four Selectable, Fixed Gain Settings
- Internal Oscillator (No External Components Required)
- Single Ended Analog Inputs
- Thermal and Short-Circuit Protection with Auto Recovery Feature
- 20-pin DIP Package

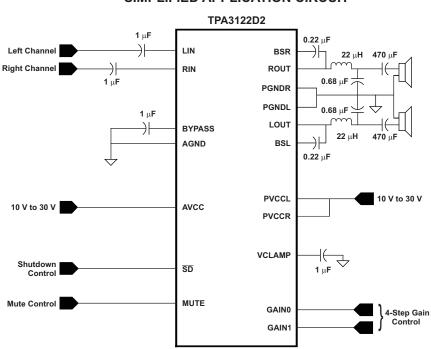
# APPLICATIONS

• Televisions

# DESCRIPTION

The TPA3122D2 is a 15-W (per channel) efficient, Class-D audio power amplifier for driving stereo single ended speakers or mono bridge tied load. The TPA3122D2 can drive stereo speakers as low as  $4\Omega$ . The efficiency of the TPA3122D2 eliminates the need for an external heat sink when playing music.

The gain of the amplifier is controlled by two gain select pins. The gain selections are 20, 26, 32, and 36 dB.



### SIMPLIFIED APPLICATION CIRCUIT

**5**3

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

N (DIP) PACKAGE (TOP VIEW)						
PVCCL SD MUTE LIN RIN BYPASS AGND AGND VCLAMP PVCCR	[ 1 [ 2 [ 3 [ 5 [ 5 [ 7 [ 8 [ 9 [ 10	U 20 19 18 17 16 15 14 13 12 11	PGNDL LOUT BSL AVCC GAIN0 GAIN1 BSR ROUT PGNDR			

#### **TERMINAL FUNCTIONS**

TERMINAL					
NAME	20-PIN (DIP)	I/O	DESCRIPTION		
SD	2	I	Shutdown signal for IC (low = disabled, high = operational). TTL logic levels with compliance to AVCC.		
RIN	5	I	Audio input for right channel.		
LIN	4	I	Audio input for left channel.		
GAIN0	15	I	Gain select least significant bit. TTL logic levels with compliance to AVCC.		
GAIN1	14	I	Gain select most significant bit. TTL logic levels with compliance to AVCC.		
MUTE	3	I	Mute signal for quick disable/enable of outputs (high = outputs switch at 50% duty cycle; low = outputs enabled). TTL logic levels with compliance to AVCC.		
BSL	18	I/O	Bootstrap I/O for left channel.		
PVCCL	1		Power supply for left channel H-bridge, not internally connected to PVCCR or AVCC.		
LOUT	19	0	Class-D -H-bridge positive output for left channel.		
PGNDL	20		Power ground for left channel H-bridge.		
VCLAMP	9		Internally generated voltage supply for bootstrap capacitors.		
BSR	13	I/O	Bootstrap I/O for right channel.		
ROUT	12	0	Class-D -H-bridge negative output for right channel.		
PGNDR	11		Power ground for right channel H-bridge.		
PVCCR	10		Power supply for right channel H-bridge, not connected to PVCCL or AVCC.		
AGND	8		Analog ground for digital/analog cells in core.		
AGND	7		Analog Ground for analog cells in core.		
BYPASS	6	0	Reference for pre-amplifier inputs. Nominally equal to AVCC/8. Also controls start-up time via external capacitor sizing.		
AVCC	16, 17		High-voltage analog power supply. Not internally connected to PVCCR or PVCCL		



# ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			VALUE	UNIT
V <sub>CC</sub>	Supply voltage, AVCC, I	PVCC	-0.3 to 36	V
VI	Logic input voltage	SD, MUTE, GAIN0, GAIN1	–0.3 to V <sub>CC</sub> +0.3 –0.3 to V <sub>CC</sub> +0.3	V
V <sub>IN</sub>	Analog input voltage	RIN, LIN	-0.3 to 7	V
	Continuous total power	dissipation	See Dissipation Rating Table	
T <sub>A</sub>	Operating free-air tempe	erature range	-40 to 85	°C
TJ	Operating junction temp	erature range	-40 to 150	°C
T <sub>stg</sub>	Storage temperature rar	nge	-65 to 150	°C
RL	Load resistance (Minimu	ım value)	3.2	kV
ESD	Electrostatia Discharge	Human body model (all pins)	±2	kV
ESD	Electrostatic Discharge	Charged-device model (all pins)	±500	V

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operations of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### **DISSIPATION RATINGS**

PACKAGE <sup>(1)</sup>	T <sub>A</sub> ≤ 25°C	DERATING FACTOR	T <sub>A</sub> = 70°C	T <sub>A</sub> = 85°C
20-pin DIP	1.87 W	15 mW/°C	1.20 W	0.97 W

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

#### **RECOMMENDED OPERATING CONDITIONS**

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	PVCC, AVCC	10	30	V
VIH	High-level input voltage	SD, MUTE, GAIN0, GAIN1	2		V
V <sub>IL</sub>	Low-level input voltage	SD, MUTE, GAIN0, GAIN1		0.8	V
		$\overline{SD}$ , $V_I = V_{CC}$ , $V_{CC} = 30 \text{ V}$		125	
I <sub>IH</sub>	High-level input current	MUTE, $V_I = V_{CC}$ , $V_{CC} = 30$ V		125	μA
		GAIN0, GAIN1, $V_I = V_{CC}$ , $V_{CC} = 24$ V		125	
		$\overline{SD}$ , V <sub>I</sub> = 0, V <sub>CC</sub> = 30 V		1	
IIL	Low-level input current	MUTE, V <sub>I</sub> = 0 V, V <sub>CC</sub> = 30 V		1	μA
		GAIN0, GAIN1, $V_I = 0 V$ , $V_{CC} = 24 V$		1	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

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# **DC CHARACTERISTICS**

 $T_{\text{A}}$  = 25°C,  $V_{\text{CC}}$  = 24 V,  $R_{\text{L}}$  = 4 $\Omega$  (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>OS</sub>	Class-D output offset voltage (measured differentially)	$V_{I} = 0 V, A_{V} = 36 d$	V <sub>I</sub> = 0 V, A <sub>V</sub> = 36 dB		7.5	50	mV
V <sub>(BYPASS)</sub>	Bypass output voltage	No load			AV <sub>CC</sub> /8		V
I <sub>CC(q)</sub>	Quiescent supply current	$\overline{SD} = 2 V, MUTE =$	0 V, No load		23	37	mA
I <sub>CC(q)</sub>	Quiescent supply current in mute mode	MUTE = 2 V, No lo	MUTE = 2 V, No load		23		mA
I <sub>CC(q)</sub>	Quiescent supply current in shutdown mode	$\overline{SD} = 0.8 \text{ V}$ , No load			0.39	1	mA
r <sub>DS(on)</sub>	Drain-source on-state resistance				200		mΩ
			Gain0 = 0.8 V	18	20	22	
<u> </u>		Gain1 = 0.8 V	Gain0 = 2 V	24	26	28	dB
G Gain			Gain0 = 0.8 V	30	32	34	uБ
		Gain1 = 2 V	Gain0 = 2 V	34	36	38	
	Mute Attenuation	V <sub>I</sub> = 1Vrms			-82		

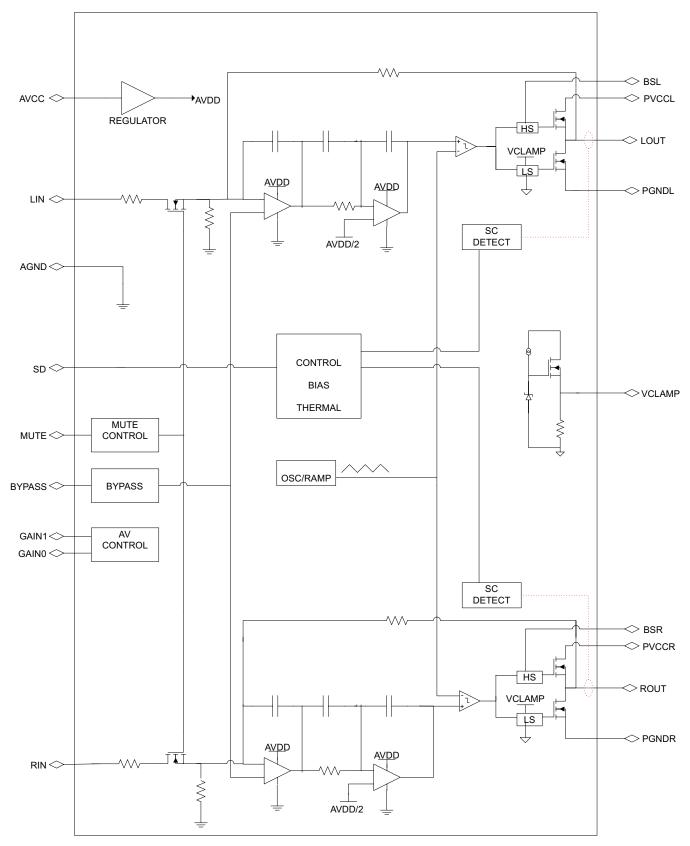
# AC CHARACTERISTICS

 $T_A = 25^{\circ}C$ ,  $V_{CC} = 24V$ ,  $R_L = 4\Omega$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
K	Cupply ripple rejection	V <sub>CC</sub> = 12 V, V <sub>ripple</sub> = 200 mV <sub>PP</sub> 100 Hz			-30		dB
K <sub>SVR</sub>	Supply ripple rejection	Gain = 20 dB	1 kHz		-48		dB
	Output Device at 40/ TUD N	$V_{CC} = 12 \text{ V}, \text{ R}_{L} = 4 \Omega, \text{ f} = 1 \text{ kHz}$			4		
D	Output Power at 1% THD+N	$V_{CC} = 24 \text{ V}, \text{ R}_{L} = 8 \Omega, \text{ f} = 1 \text{ kHz}$			8		14/
Po	Output Power at 10%	$V_{CC} = 12 \text{ V}, \text{ R}_{L} = 4 \Omega, \text{ f} = 1 \text{ kHz}$			5		W
	THD+N	$V_{CC} = 24 \text{ V}, \text{ R}_{L} = 8 \Omega, \text{ f} = 1 \text{ kHz}$			10		
THD+N Total harmonic distortion + noise		$R_L = 4 \Omega$ , f = 1 kHz, $P_O = 1 W$			0.1%		
		$R_L = 8 \Omega$ , f = 1 kHz, $P_O = 1 W$			0.06%		
		20 Lista 20 Lilis A unichtad filtar Cain 20 dD			85		μV
V <sub>n</sub>	Output integrated noise floor	20 Hz to 22 kHz, A-weighted filter, Gain	= 20 0B		-80		dB
	Crosstalk	$P_0 = 1 \text{ W}, \text{ f} = 1 \text{ kHz}; \text{ Gain} = 20 \text{ dB}$			-60		dB
SNR	Signal-to-noise ratio	Max Output at THD+N < 1%, f = 1 kHz,	Gain = 20 dB		99		dB
	Thermal trip point				150		°C
	Thermal hysteresis				30		°C
f <sub>OSC</sub>	Oscillator frequency	$10 \text{ V} \leq \text{V}_{\text{CC}}$		230	250	270	kHz
Δt	mute delay	time from mute input switches high until	outputs muted		120		msec
Δι	unmute delay	time from mute input switches low until of	outputs unmuted		120		msec

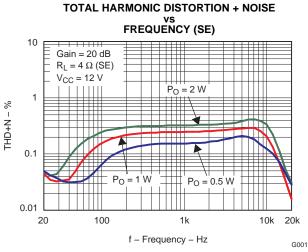


FUNCTIONAL BLOCK DIAGRAM



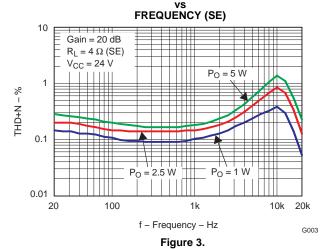


# **TYPICAL CHARACTERISTICS**

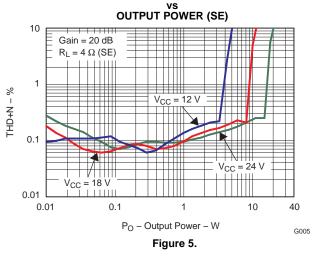












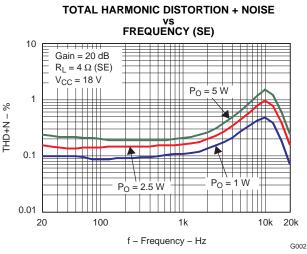
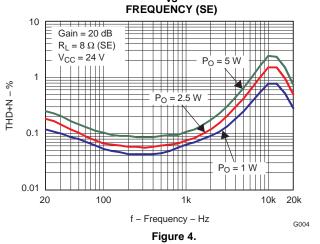
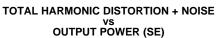
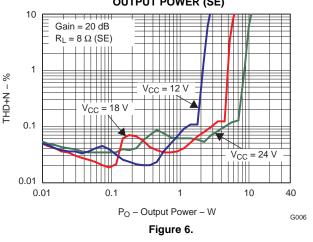


Figure 2.

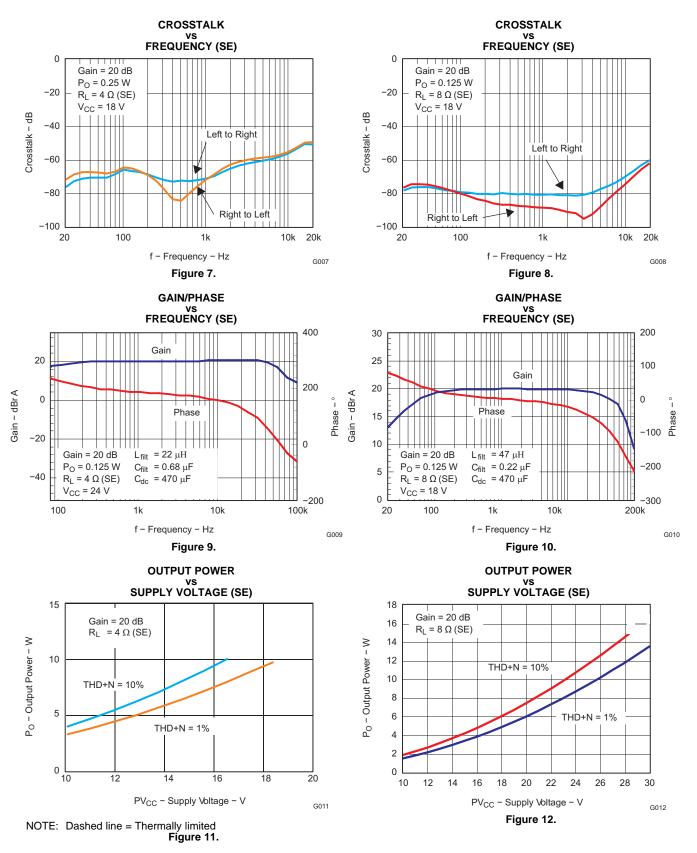
TOTAL HARMONIC DISTORTION + NOISE





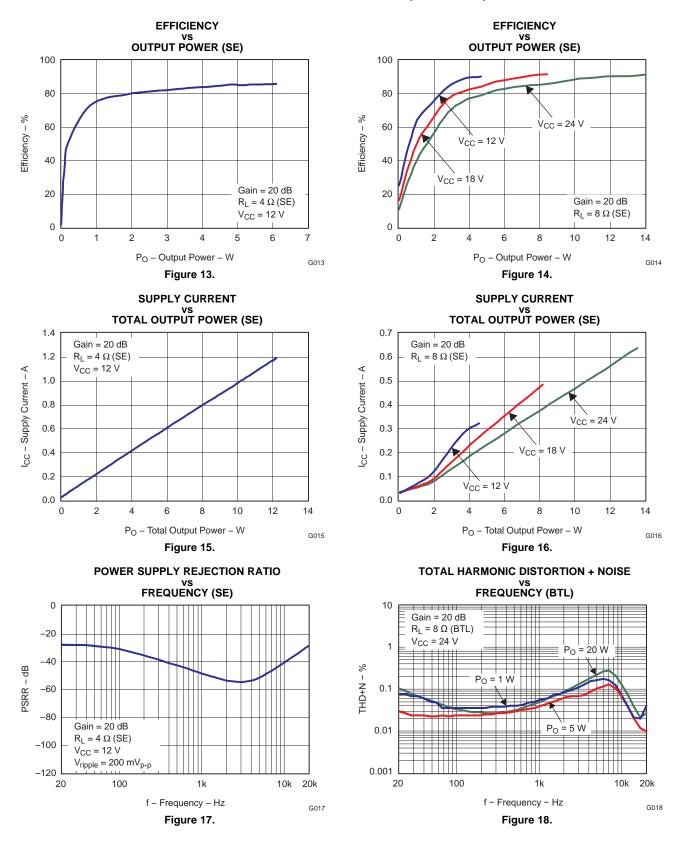


# **TYPICAL CHARACTERISTICS (continued)**



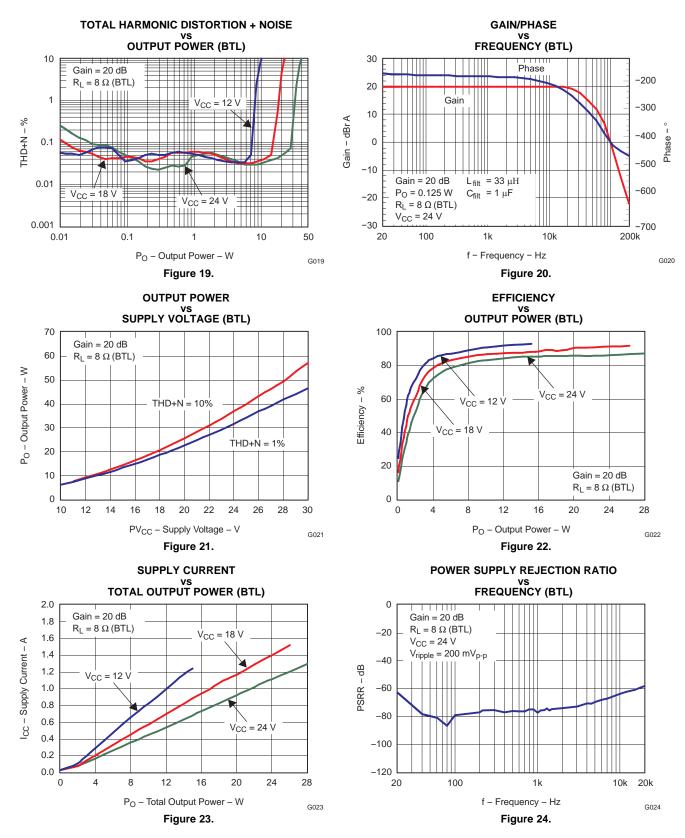


# **TYPICAL CHARACTERISTICS (continued)**





# **TYPICAL CHARACTERISTICS (continued)**





# APPLICATION INFORMATION

#### **CLASS-D OPERATION**

This section focuses on the class-D operation of the TPA3122D2.

#### **Traditional Class-D Modulation Scheme**

The TPA3122D2 operates in AD mode. There are two main configurations that may be used. For stereo operation, the TPA3122D2 should be configured in a single-ended (SE) half bridge amplifier. For mono applications, TPA3122D2 may be used as a bridge tied load (BTL) amplifier. The traditional class-D modulation scheme, which is used in the TPA3122D2 BTL configuration, has a differential output where each output is 180 degrees out of phase and changes from ground to the supply voltage,  $V_{CC}$ . Therefore, the differential pre-filtered output varies between positive and negative  $V_{CC}$ , where filtered 50% duty cycle yields 0 V across the load. The traditional class-D modulation scheme with voltage and current waveforms is shown in Figure 25.

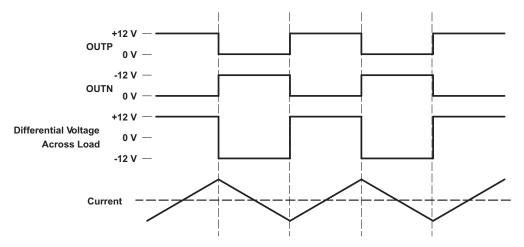


Figure 25. Traditional Class-D Modulation Scheme's Output Voltage and Current Waveforms into an Inductive Load With No Input

## Supply Pumping

One issue encountered in single-ended (SE) class-D amplifier designs is supply pumping. Power-supply pumping is a rise in the local supply voltage due to energy being driven back to the supply by operation of the class-D amplifier. This phenomenon is most evident at low audio frequencies and when both channels are operating at the same frequency and phase. At low levels, power-supply pumping results in distortion in the audio output due to fluctuations in supply voltage. At higher levels, pumping can cause the overvoltage protection to operate, which temporarily shuts down the audio output.

Several things can be done to relieve power-supply pumping. The lowest impact is to operate the two inputs out of phase 180° and reverse the speaker connections. Because most audio is highly correlated, this causes the supply pumping to be out of phase and not as severe. If this is not enough, the amount of bulk capacitance on the supply must be increased. Also, improvement is realized by hooking other supplies to this node, thereby, sinking some of the excess current. Power-supply pumping should be tested by operating the amplifier at low frequencies and high output levels.

#### Gain setting via GAIN0 and GAIN1 inputs

The gain of the TPA3122D2 is set by two input terminals, GAIN0 and GAIN1.

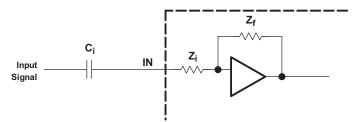
The gains listed in Table 1 are realized by changing the taps on the input resistors and feedback resistors inside the amplifier. This causes the input impedance ( $Z_1$ ) to be dependent on the gain setting. The actual gain settings are controlled by ratios of resistors, so the gain variation from part-to-part is small. However, the input impedance from part-to-part at the same gain may shift by ±20% due to shifts in the actual resistance of the input resistors.

For design purposes, the input network (discussed in the next section) should be designed assuming an input impedance of 8 k $\Omega$ , which is the absolute minimum input impedance of the TPA3122D2. At the higher gain settings, the input impedance could increase as high as 72 k $\Omega$ 

0.41514	GAIN0	AMPLIFIER GAIN (dB)	INPUT IMPEDANCE (kΩ)		
GAIN1	GAINU	TYPICAL	TYPICAL		
0	0	20	60		
0	1	26	30		
1	0	32	15		
1	1	36	9		

## INPUT RESISTANCE

Changing the gain setting can vary the input resistance of the amplifier from its smallest value, 10 k $\Omega$  ±20%, to the largest value, 60 k $\Omega$  ±20%. As a result, if a single capacitor is used in the input high-pass filter, the -3 dB or cutoff frequency may change when changing gain steps.

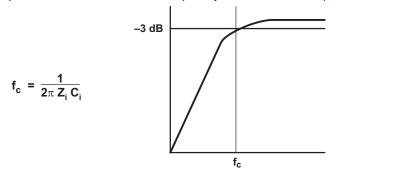


The -3-dB frequency can be calculated using Equation 1. Use the Z<sub>I</sub> values given in Table 1.

$$f = \frac{1}{2\pi Z_i C_i}$$
(1)

## INPUT CAPACITOR, C<sub>1</sub>

In the typical application, an input capacitor  $_1$ ) is required to allow the amplifier to bias the input signal to the proper dc level for optimum operation. In this case, C<sub>1</sub> and the input impedance of the amplifier (Z<sub>1</sub>) form a high-pass filter with the corner frequency determined in Equation 2.



(2)

The value of C<sub>1</sub> is important, as it directly affects the bass (low-frequency) performance of the circuit. Consider the example where Z<sub>1</sub> is 20 k $\Omega$  and the specification calls for a flat bass response down to 20 Hz. Equation 2 is reconfigured as Equation 3.

$$C_i = \frac{1}{2\pi Z_i f_c}$$

(3)

In this example,  $C_1$  is 0.4  $\mu$ F; so, one would likely choose a value of 0.47  $\mu$ F as this value is commonly used. If the gain is known and is constant, use  $Z_1$  from Table 1 to calculate  $C_1$ . A further consideration for this capacitor is the leakage path from the input source through the input network \_\_\_\_\_\_) and the feedback network to the load. This leakage current creates a dc offset voltage at the input to the amplifier that reduces useful headroom, especially

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in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the dc level there is held at 2 V, which is likely higher than the source dc level. Note that it is important to confirm the capacitor polarity in the application. Additionally, lead-free solder can create dc offset voltages and it is important to ensure that boards are cleaned properly.

# Single Ended Output Capacitor, C<sub>o</sub>

In single ended (SE) applications, the DC blocking capacitor forms a high pass filter with speaker impedance. The frequency response rolls of with decreasing frequency at a rate of 20dB/decade. The cutoff frequency is determined by

 $fc = 1/2 \times \pi C_o Z_L$ 

Table 2 shows some common component values and the associated cutoff frequencies:

Speaker Impedance (Ω)	C <sub>SE</sub> – DC Blockii	ng Capacitor (μF)	
Speaker impedance (12)	$f_c = 60 Hz$	f <sub>c</sub> = 40 Hz	f <sub>c</sub> = 20 Hz
4	680	1000	2200
8	330	470	1000

#### Table 2. Common Filter Responses

#### **Output Filter and Frequency Response**

For the best frequency response, a flat passband output filter (second order Butterworth) may be used. The output filter components consist of the series inductor and capacitor to ground at the LOUT and ROUT pins. There are several possible configurations depending on the speaker impedance and whether the output configuration is Single Ended (SE) or Bridge Tied Load (BTL). Table 3 list several possible arrangements.

Output Configuration	Speaker Impedance (Ω)	Filter Inductor (µH)	Filter Capacitor (nF)
Single Ended (SE)	4	22	680
	8	47	390
Deides Tieddaed	4	10	1500
Bridge Tied Load	8	22	680

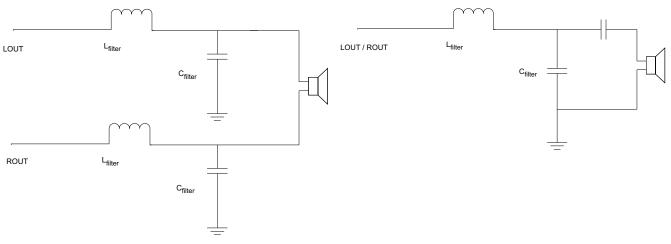


Figure 26. BTL Filter Configuration

Figure 27. SE Filter Configuration



#### Power Supply Decoupling, C<sub>S</sub>

The TPA3122D2 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure that the output total harmonic distortion (THD) is as low as possible. Power supply decoupling also prevents oscillations for long lead lengths between the amplifier and the speaker. The optimum decoupling is achieved by using two capacitors of different types that target different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1  $\mu$ F to 1  $\mu$ F placed as close as possible to the device V<sub>CC</sub> lead works best. For filtering lower frequency noise signals, a larger aluminum electrolytic capacitor of 220  $\mu$ F or greater placed near the audio power amplifier is recommended. The 220- $\mu$ F capacitor also serves as local storage capacitor for supplying current during large signal transients on the amplifier outputs. The PVCC terminals provide the power to the output transistors, so a 220- $\mu$ F or larger capacitor should be placed on each PVCC terminal. A 10- $\mu$ F capacitor on the AVCC terminal is adequate.

#### **BSN and BSP Capacitors**

The half H-bridge output stages use only NMOS transistors. Therefore, they require bootstrap capacitors for the high side of each output to turn on correctly. A 220-nF ceramic capacitor, rated for at least 25 V, must be connected from each output to its corresponding bootstrap input. Specifically, one 220-nF capacitor must be connected from LOUT to BSL, and one 220-nF capacitor must be connected from ROUT to BSR.

The bootstrap capacitors connected between the BSx pins and corresponding output function as a floating power supply for the high-side N-channel power MOSFET gate drive circuitry. During each high-side switching cycle, the bootstrap capacitors hold the gate-to-source voltage high enough to keep the high-side MOSFETs turned on.

#### VCLAMP Capacitor

To ensure that the maximum gate-to-source voltage for the NMOS output transistors is not exceeded, one internal regulator clamps the gate voltage. One  $1-\mu F$  capacitor must be connected from VCLAMP (pin 11 for PWP and pin 9 for DIP package) to ground and must be rated for at least 16 V. The voltages at the VCLAMP terminal may vary with V<sub>CC</sub> and may not be used for powering any other circuitry.

#### V<sub>BYP</sub> Capacitor Selection

The scaled supply reference ( $V_{BYP}$ ) nominally provides an AVcc/8 internal bias for the preamplifier stages. The external capacitor for this reference  $C_{BYP}$ ) is a critical component and serves several important functions. During start-up or recovery from shutdown mode,  $C_{BSP}$  determines the rate at which the amplifier starts up. The second function is to reduce noise produced by the power supply caused by coupling with the output drive signal. This noise could result in degraded PSRR and THD + N.

The circuit is designed for a  $C_{BSP}$  value of 1  $\mu$ F for best pop performance. The inputs caps should be the same value. A ceramic or tantalum low-ESR capacitor is recommended.

## SHUTDOWN OPERATION

The TPA3122D2 employs a shutdown mode of operation designed to reduce supply current ( $I_{CC}$ ) to the absolute minimum level during periods of non-use for power conservation. The SHUTDOWN input terminal should be held high (see specification table for trip point) during normal operation when the amplifier is in use. Pulling SHUTDOWN low causes the outputs to mute and the amplifier to enter a low-current state. Never leave SHUTDOWN unconnected, because amplifier operation would be unpredictable.

For the best power-up pop performance, place the amplifier in the shutdown or mute mode prior to applying the power supply voltage.

#### **MUTE Operation**

The MUTE pin is an input for controlling the output state of the TPA3122D2. A logic high on this terminal causes the outputs to run at a constant 50% duty cycle. A logic low on this pin enables the outputs. This terminal may be used as a quick disable/enable of outputs when changing channels on a television or switching between different audio sources.

The MUTE terminal should never be left floating. For power conservation, the SHUTDOWN terminal should be used to reduce the quiescent current to the absolute minimum level.

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### USING LOW-ESR CAPACITORS

Low-ESR capacitors are recommended throughout this application section. A real (as opposed to ideal) capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance, the more the real capacitor behaves like an ideal capacitor.

### SHORT-CIRCUIT PROTECTION

The TPA3122D2 has short-circuit protection circuitry on the outputs that prevents damage to the device during output-to-output shorts and output-to-GND shorts. When a short circuit is detected on the outputs, the part immediately disables the output drive. This is an unlatched fault. Normal operation is restored when the fault is removed.

# THERMAL PROTECTION

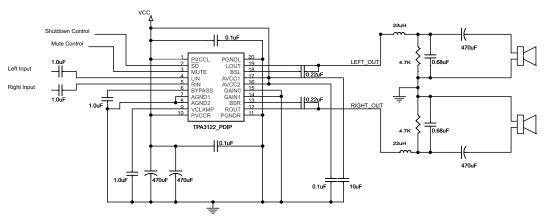
Thermal protection on the TPA3122D2 prevents damage to the device when the internal die temperature exceeds  $150^{\circ}$ C. There is a  $\pm 15^{\circ}$ C tolerance on this trip point from device to device. Once the die temperature exceeds the thermal set point, the device enters into the shutdown state and the outputs are disabled. This is not a latched fault. The thermal fault is cleared once the temperature of the die is reduced by  $30^{\circ}$ C. The device begins normal operation at this point with no external system interaction.

## PRINTED-CIRCUIT BOARD (PCB) LAYOUT

Because the TPA3122D2 is a class-D amplifier that switches at a high frequency, the layout of the printed-circuit board (PCB) should be optimized according to the following guidelines for the best possible performance.

- Decoupling capacitors—The high-frequency 0.1μF decoupling capacitors should be placed as close to the PVCC (pins 1 and 10) and AVCC (pins 16 and 17) terminals as possible. The VBYP (pin 6) capacitor and VCLAMP (pin 9) capacitor should also be placed as close to the device as possible. Large (220 μF or greater) bulk power supply decoupling capacitors should be placed near the TPA3122D2 on the PVCCL and PVCCR terminals.
- Grounding—The AVCC (pins 16 and 17) decoupling capacitor and VBYP (pin 6) capacitor should each be grounded to analog ground (AGND, pins 7 and 8). The PVCCx decoupling capacitors and VCLAMP capacitors should each be grounded to power ground (PGND, pins 11 and 20). Analog ground and power ground should be connected at the thermal pad, which should be used as a central ground connection or star ground for the TPA3122D2.
- Output filter—The EMI filter (L1, L2, C9, and C16) should be placed as close to the output terminals as possible for the best EMI performance. The capacitors should be grounded to power ground.

For an example layout, see the TPA3122D2 Evaluation Module (TPA3122D2EVM) User Manual, (SLOU214). Both the EVM user manual and the thermal pad application note are available on the TI Web site at http://www.ti.com.





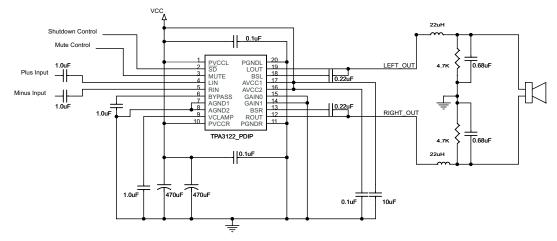


Figure 29. BTL 8-Ω Application Schematic

## BASIC MEASUREMENT SYSTEM

This application note focuses on methods that use the basic equipment listed below:

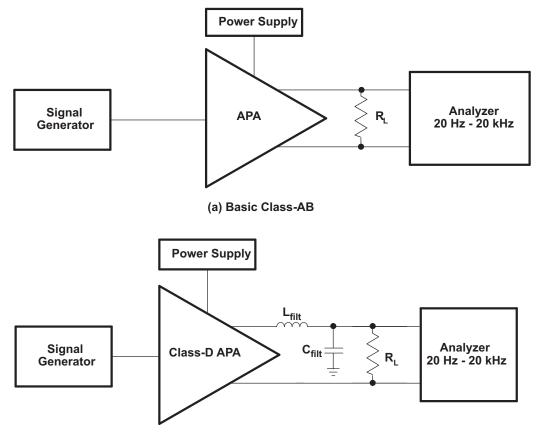
- Audio analyzer or spectrum analyzer
- Digital multimeter (DMM)
- Oscilloscope
- Twisted-pair wires
- Signal generator
- Power resistor(s)
- Linear regulated power supply
- Filter components
- EVM or other complete audio circuit

Figure 30 shows the block diagrams of basic measurement systems for class-AB and class-D amplifiers. A sine wave is normally used as the input signal because it consists of the fundamental frequency only (no other harmonics are present). An analyzer is then connected to the APA output to measure the voltage output. The analyzer must be capable of measuring the entire audio bandwidth. A regulated dc power supply is used to reduce the noise and distortion injected into the APA through the power pins. A System Two audio measurement system (AP-II) (Reference 1) by Audio Precision includes the signal generator and analyzer in one package.

The generator output and amplifier input must be ac-coupled. However, the EVMs already have the ac-coupling capacitors,  $C_{IN}$ ), so no additional coupling is required. The generator output impedance should be low to avoid attenuating the test signal, and is important because the input resistance of APAs is not high. Conversely, the analyzer-input impedance should be high. The output resistance,  $R_{OUT}$ , of the APA is normally in the hundreds of milliohms and can be ignored for all but the power-related calculations.

Figure 30(a) shows a class-AB amplifier system. It takes an analog signal input and produces an analog signal output. This amplifier circuit can be directly connected to the AP-II or other analyzer input.

This is not true of the class-D amplifier system shown in Figure 30(b), which requires low-pass filters in most cases in order to measure the audio output waveforms. This is because it takes an analog input signal and converts it into a pulse-width modulated (PWM) output signal that is not accurately processed by some analyzers.



(b) Traditional Class-D

Figure 30. Audio Measurement Systems



#### SE Input and SE Output (TPA3122D2 Stereo Configuration)

The SE input and output configuration is used with class-AB amplifiers. A block diagram of a fully SE measurement circuit is shown in Figure 31. SE inputs normally have one input pin per channel. In some cases, two pins are present; one is the signal and the other is ground. SE outputs have one pin driving a load through an output ac coupling capacitor and the other end of the load is tied to ground. SE inputs and outputs are considered to be unbalanced, meaning one end is tied to ground and the other to an amplifier input/output.

The generator should have unbalanced outputs, and the signal should be referenced to the generator ground for best results. Unbalanced or balanced outputs can be used when floating, but they may create a ground loop that will effect the measurement accuracy. The analyzer should have balanced inputs to cancel out any common-mode noise in the measurement.

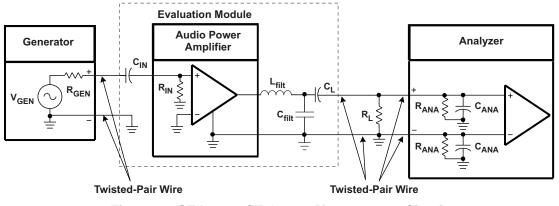


Figure 31. SE Input—SE Output Measurement Circuit

The following general rules should be followed when connecting to APAs with SE inputs and outputs:

- Use an unbalanced source to supply the input signal.
- Use an analyzer with balanced inputs.
- Use twisted pair wire for all connections.
- Use shielding when the system environment is noisy.
- Ensure the cables from the power supply to the APA, and from the APA to the load, can handle the large currents (see Table 4)

# DIFFERENTIAL INPUT AND BTL OUTPUT (TPA3122D2 Mono Configuration)

Many of the class-D APAs and many class-AB APAs have differential inputs and bridge-tied load (BTL) outputs. Differential inputs have two input pins per channel and amplify the difference in voltage between the pins. Differential inputs reduce the common-mode noise and distortion of the input circuit. BTL is a term commonly used in audio to describe differential outputs. BTL outputs have two output pins providing voltages that are 180 degrees out of phase. The load is connected between these pins. This has the added benefits of quadrupling the output power to the load and eliminating a dc blocking capacitor.

A block diagram of the measurement circuit is shown in Figure 32. The differential input is a balanced input, meaning the positive (+) and negative (-) pins have the same impedance to ground. Similarly, the SE output equates to a balanced output.

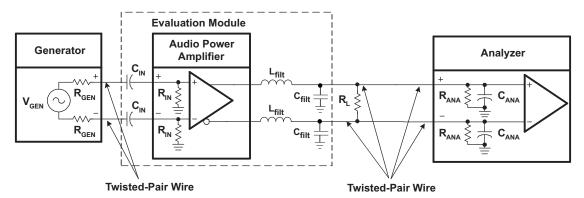


Figure 32. Differential Input, BTL Output Measurement Circuit

The generator should have balanced outputs, and the signal should be balanced for best results. An unbalanced output can be used, but it may create a ground loop that affects the measurement accuracy. The analyzer must also have balanced inputs for the system to be fully balanced, thereby cancelling out any common-mode noise in the circuit and providing the most accurate measurement.

The following general rules should be followed when connecting to APAs with differential inputs and BTL outputs:

- Use a balanced source to supply the input signal.
- Use an analyzer with balanced inputs.
- Use twisted-pair wire for all connections.
- Use shielding when the system environment is noisy.
- Ensure that the cables from the power supply to the APA, and from the APA to the load, can handle the large currents (see Table 4).

Table 4 shows the recommended wire size for the power supply and load cables of the APA system. The real concern is the dc or ac power loss that occurs as the current flows through the cable. These recommendations are based on 12-inch long wire with a 20-kHz sine-wave signal at 25°C.

Table 4. Recommended	Minimum	Wire	Size for	Power	Cables	

P <sub>OUT</sub> (W)	R <sub>L</sub> (Ω)	AWG	AWG Size		DC POWER LOSS (MW)		AC POWER LOSS (MW)	
10	4	18	22	16	40	18	42	
2	4	18	22	3.2	8	3.7	8.5	
1	8	22	28	2	8	2.1	8.1	
< 0.75	8	22	28	1.5	6.1	1.6	6.2	

# PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing		kage Ity	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPA3122D2N	ACTIVE	PDIP	Ν	20 2	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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